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PPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/851,905	05/09/2001	Thomas Sonderman	2000.044700	3951
23720	7590 12/07/20	)4	EXAMINER	
WILLIAMS, MORGAN & AMERSON, P.C.			JARRETT, RYAN A	
HOUSTON,	MOND, SUITE 1100 TX 77042	•	ART UNIT	PAPER NUMBER
,	•		2125	<u> </u>

DATE MAILED: 12/07/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

<u> </u>	Application No.	Applicant(s)	
	09/851,905	SONDERMAN ET AL.	
Office Action Summary	Examiner	Art Unit	_
	Ryan A. Jarrett	2125	
The MAILING DATE of this communication Period for Reply	appears on the cover sheet wi	th the correspondence address	
A SHORTENED STATUTORY PERIOD FOR RE THE MAILING DATE OF THIS COMMUNICATIO  - Extensions of time may be available under the provisions of 37 CF after SIX (6) MONTHS from the mailing date of this communication  - If the period for reply specified above is less than thirty (30) days, a  - If NO period for reply is specified above, the maximum statutory pe  - Failure to reply within the set or extended period for reply will, by st Any reply received by the Office later than three months after the meanned patent term adjustment. See 37 CFR 1.704(b).	ON. R 1.136(a). In no event, however, may a r. a reply within the statutory minimum of thirt niod will apply and will expire SIX (6) MON tatute, cause the application to become AB	eply be timely filed  y (30) days will be considered timely.  THS from the mailing date of this communication.  ANDONED (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on 1	<u> 4 September 2004</u> .		
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ -	This action is non-final.		
3) Since this application is in condition for allocation closed in accordance with the practice und	•	•	
Disposition of Claims			
4)⊠ Claim(s) <u>1,3-11,13-21,23-41 and 43-61</u> is/a 4a) Of the above claim(s) is/are with 5)□ Claim(s) is/are allowed. 6)⊠ Claim(s) <u>1,3-11,13-21,23-41,43-61</u> is/are re 7)□ Claim(s) is/are objected to. 8)□ Claim(s) are subject to restriction and	drawn from consideration.		
Application Papers			
9)☐ The specification is objected to by the Exan	niner.		
10)☐ The drawing(s) filed on is/are: a)☐	•		
Applicant may not request that any objection to		• •	
Replacement drawing sheet(s) including the country.  11) The oath or declaration is objected to by the	•		
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for fore a) All b) Some * c) None of:  1. Certified copies of the priority document	nents have been received.  Itents have been received in A priority documents have been reau (PCT Rule 17.2(a)).	oplication No received in this National Stage	
Attachment(s)			
1) Notice of References Cited (PTO-892)		ummary (PTO-413)	
<ol> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statement(s) (PTO-1449 or PTO/SB Paper No(s)/Mail Date</li> </ol>	·	)/Mail Date formal Patent Application (PTO-152) 	

#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 112

1. The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

2. Claims 1, 3-11, 13-21, 23-41, and 43-61 are rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention.

Regarding claims 1, 11, 21, 31, 41, 51, and 61, applicant recites "using deposition rate sensor data for performing said modeling". However, Examiner has been unable to find any disclosure of "deposition rate sensors" in the original specification.

Claims 3-10 depend from claim 1, claims 13-20 depend from claim 11, claims 23-30 depend from claim 21, claims 32-40 depend from claim 31, claims 43-50 depend from claim 41, and claims 52-60 depend from claim 51 and thus incorporate the same deficiencies.

This claimed feature was added to the claims in an amendment filed 5/6/03.

Application/Control Number: 09/851,905

Art Unit: 2125

3. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Page 3

4. Claims 1, 3-11, 13-21, 23-30, 41, and 43-61 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Regarding claims 1, 11, 21, 41, 51, and 61, the limitation "modeling said dependence of the deposition rate (on at least one of deposition plasma power and deposition time) being based upon a target life of the sputter target" is unclear in the context of the claim. It is unclear what exactly the dependence of the deposition rate is being modeled against.

It is understood that a dependence of the deposition rate on at least one of the plasma power and deposition time is modeled. But it is unclear how this dependence is additionally "based upon a target life of the sputter target". It is understood from the Applicant's specification that the deposition rate is dependent on the life or age of the sputter target, however, that is not what is being claimed in claims 1, 11, 21, 41, 51, and 61.

Claims 3-10 depend from claim 1, claims 13-20 depend from claim 11, claims 23-30 depend from claim 21, claims 43-50 depend from claim 41, and claims 52-60 depend from claim 51 and thus incorporate the same deficiencies.

This claimed feature was added to the claims in an amendment filed 8/29/03.

# Claim Rejections - 35 USC § 102

5. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

6. As best understood, claims 1, 5, 6, 9-11, 15, 16, 19-21, 25, 26, 29-32, 35, 36, 39-41, 45, 46, 49-52, 55, 56, 59, and 60 are rejected under 35 U.S.C. 102(b) as being anticipated by Turner U.S. Patent No. 4,1666,783. Turner discloses a method, program storage device, computer, and system comprising: monitoring consumption of a sputter target to determine a deposition rate (using deposition rate sensors) of a metal layer during metal deposition processing using the sputter target (col. 1 lines 34-37, col. 3 line 64 – col. 4 line 7); modeling a dependence of the deposition rate on the deposition plasma power (col. 3 lines 23-32); and applying the deposition rate model to modify the metal deposition processing to form the metal layer to have or approach a desired thickness (col. 3 lines 12-16, col. 3 lines 32-36);

wherein monitoring the consumption of the sputter target to determine the deposition rate of the metal layer during the metal deposition processing comprises modeling a dependence of the deposition rate on a target life of the sputter target (col. 3 lines 23-32);

wherein applying the deposition rate model to modify the metal deposition processing comprises inverting the deposition rate model to determine the deposition plasma power to form the metal layer to have the desired thickness (col. 3 lines 32-36);

wherein modeling the dependence of the deposition rate on the deposition plasma power (implied) and target life (Fig. 1) of the sputter target comprises fitting previously collected metal deposition processing data using at least one of polynomial curve fitting, polynomial least-squares fitting, non-polynomial least-squares fitting, weighted least-squares fitting, weighted polynomial least-squares fitting, and weighted non-polynomial least-squares fitting (Fig. 1 illustrates the modeling of the dependence of deposition rate on sputter target life using least-squares fitting – it is implied that the dependence of deposition rate on deposition plasma power is modeled in a similar fashion);

wherein modeling the dependence of the deposition rate on the target life of the sputter target comprises modeling the dependence of the deposition rate on target lives of a plurality of previously processed sputter targets (col. 2 lines 10-13).

# Claim Rejections - 35 USC § 103

- 7. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 8. As best understood, claims 3, 4, 7, 8, 13, 14, 17, 18, 23, 24, 27, 28, 33, 34, 37, 38, 43, 44, 47, 48, 53, 54, 57, 58, and 61 are rejected under 35 U.S.C. 103(a) as being unpatentable over Turner in view of Sullivan et al. U.S. Patent No. 6,217,720. Turner does not specifically disclose "modeling a dependence of the deposition rate on the

deposition time or inverting the deposition rate model to determine the deposition time to form the metal layer having a desired thickness." However, Sullivan et al. discloses a multi-layer reactive sputtering method comprising modeling the dependence of a deposition rate on a deposition time and determining the time required to form a metal layer having the desired thickness (e.g. Fig. 5, col. 7 line 50 – col. 8 line 10, col. 8 line 60 – col. 9 line 15). Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to combine the teachings of Sullivan et al. with the system of Turner since Sullivan et al. teaches that modeling a dependence of a sputtering deposition rate on the deposition time can assist in optimizing a desired layer thickness using a relatively high deposition rate and short deposition time.

9. As best understood, claims 9, 10, 19, 20, 29, 30, 39, 40, 49, 50, 59, and 60 are additionally rejected under 35 U.S.C. 103(a) as being unpatentable over *Turner* as applied to claims 1, 2, 11, 12, 21, 22, 31, 32, 41, 42, 51, and 52 above. *Turner* does disclose modeling the dependence of deposition rate on deposition power as noted above. However, *Turner* does not explicitly disclose that the dependence of deposition rate on deposition power is modeled using the curve-fitting techniques of the claimed invention.

However, *Turner* does disclose in Fig. 1 modeling the dependence of deposition rate on sputter target life using curve-fitting techniques. Additionally, it is well known in the art to use the various curve-fitting techniques of the claimed invention to model historical data. Therefore, it would have been obvious to one having ordinary skill in the

Art Unit: 2125

art at the time the invention was made to modify *Turner* to include the capability to model the dependence of deposition rate on deposition power using the various curve-fitting techniques since *Turner* already discloses curve-fitting as a means to *accurately* model the dependence of deposition rate on target life, and also since the multiple curve-fitting techniques of the claimed invention are well-known in the art.

### Conclusion

10. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ryan A. Jarrett whose telephone number is (571) 272-3742. The examiner can normally be reached on 10:00-6:30 M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Leo Picard can be reached on (571) 272-3749. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Application/Control Number: 09/851,905 Page 8

Art Unit: 2125

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Ryan A. Jarrett Examiner Art Unit 2125

11/30/04

LEO PICARD SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2100

L. P. P.